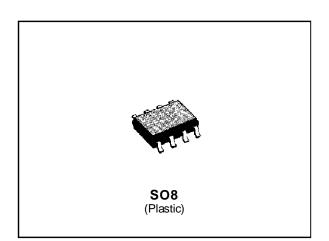


ITA6V5B1 / ITA10B1 ITA18B1 / ITA25B1

MONOLITHIC TRANSIL[®] ARRAY FOR DATA LINE PROTECTION

FEATURES

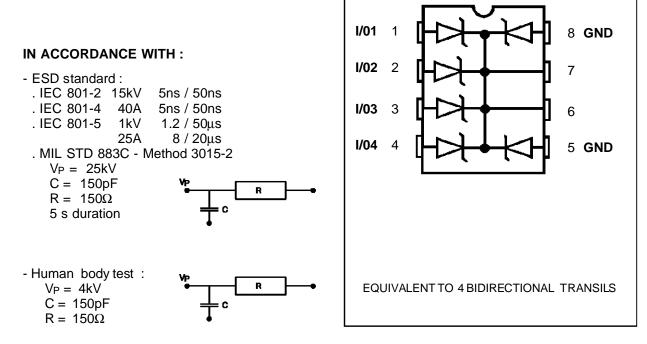
- HIGH SURGE CAPABILITY TRANSIL ARRAY IPP = 40 A 8/20µs
- UP TO 5 BIDIRECTIONAL TRANSIL FUNCTIONS
- BREAK DOWN VOLTAGE AND MAXIMUM DIFFERENTIAL VOLTAGE BETWEEN TWO INPUT PINS : ITA6V5 = 6.5 V ITA10 = 10 V ITA18 = 18 V ITA25 = 25 V
- LOW CLAMPING FACTOR (VCL / VBR) AT HIGH CURRENT LEVEL
- LOW LEAKAGE CURRENT
- LOW INPUT CAPACITANCE



FUNCTIONAL DIAGRAM

DESCRIPTION

This is a specific transil array for RS232, RS423 interface protection developed in monolithic chip form in order to provide a high surge capability and a low clamping voltage

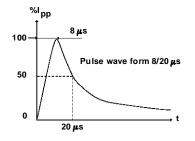


ITA6V5B1/ ITA10B1 / ITA18B1 / ITA25B1

ABSOLUTE RATINGS (limiting values) ($0^{\circ}C \le Tamb \le 70^{\circ}C$)

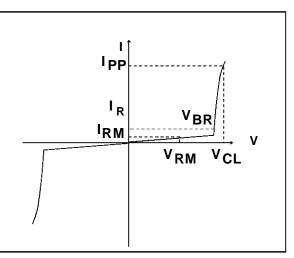
Symbol	Parameter	Value	Unit	
IPP	Peak pulse current for 8/20 µsexponential pulse	See note	40	А
l ² t	Wire I ² t value	See note	0.6	A ² s
T _{stg} Tj	Storage and Junction Temperature Range	- 55 to + 150 125	°C °C	

Note: For surges greater than the maximum value specified, the input/output will present first a short circuit to the common bus line and after an open circuit caused by the wire.



ELECTRICAL CHARACTERISTICS

Symbol	Parameter
IRM	Leakage Current @ V _{RM}
V _{RM}	Stand-off Voltage
VBR	Breakdown Voltage
VCL	Clamping Voltage
IPP	Surge Current
С	Input Capacitance



Types	I _{RM} ([⊉] V _{RM}	VBR	@ R	VCL	@ Ipp	VCL	@ Þ P	C1	C2	αΤ
	max		min			8/20µs	max	8/20µs	max	max	max
			Note 1		Note 1		Note 1		Note 2	Note 3	
	μΑ	v	v	mA	v	Α	v	Α	рF	pF	10 ⁻⁴ /°C
ITA6V5B1	50	5	6.5	1	10	10	12	25	750	550	4
ITA10B1	10	8	10	1	15	10	19	25	570	260	8
ITA18B1	4	15	18	1	25	10	28	25	350	180	9
ITA25B1	4	24	25	1	33	10	38	25	300	100	12

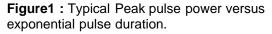
All parameters tested at 25ÉC, except where indicated.

 Note 1:
 Between I/O pin and ground.

 Note 2:
 Between two input Pins at 0 V Bias.

 Note 3:
 Between two input Pins at V_{RM}.





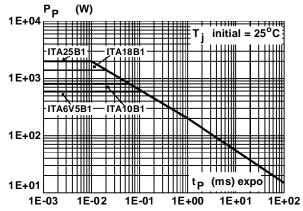
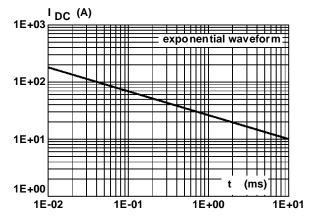


Figure 3 : Peak current I_{DC} inducing open circuit of the wire for one input/output versus pulse duration (typical values).



Note : The curve of the figure 2 is specified for a junction temperature of 25°C before surge.

Figure 2 : Clamping voltage versus peak pulse current exponential waveform 8/20 μs.

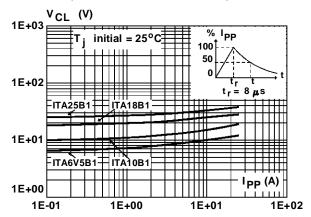
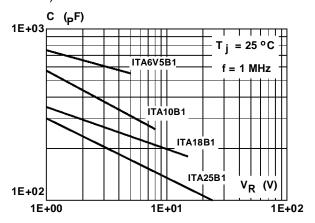


Figure 4 : Junction capacitance versus reverse applied voltage for one input/output (typical values).





ITA6V5B1/ ITA10B1 / ITA18B1 / ITA25B1

APPLICATION NOTICE

Types	Maximum differential voltage between two input pins at 25°C				
	V				
ITA6V5B1	6.5				
ITA10B1	10				
ITA18B1	18				
ITA25B1	25				

INSTRUCTION GUIDE

This monolithic Transil Array is based on 6 Unidirectional Transils with a common cathode and can be configurated to offer 4 or 5 bidirectional functions, according to the following customer application.

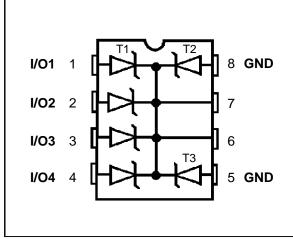


Figure 5 : Equivalent to 4 Bidirectional Transils

1/01 1 1 7 8 GND 1/02 2 1 7 7 1/03 3 1 6 6 1/04 4 1 5 1/05

Figure 6 : Equivalent to 5 Bidirectional Transils

UTILIZATION AS A BIDIRECTIONAL TRANSIL ARRAY WITH 4 I/Os.

The main application of this device is to be configurated as a 4, bidirectional Transil Array as per the Pin-out of Fig 5. Pins 5 and 8 are connected to ground. INPUTS/OUTPUTS are from Pin 1 to Pin 4.

Note : The bidirectional function is made with 2 unidirectional Transils. One (T1) is connected to the INPUT/OUTPUT, the other one (T2) is connected to the ground (see Fig 5). Ground is connected via 2 diodes T2 and T3. This allows to withstand 2 specified surges on 2 different lines at the same time.

UTILIZATION AS A BIDIRECTIONAL TRANSIL ARRAY WITH 5 I/Os.

The ITAxxB1 can be used as a 5 bidirectional Transil Array.

Ground can be connected to any pin (except 6 and 7).

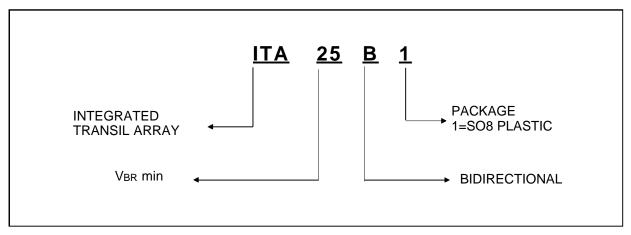
The other pins are used as INPUTS and OUTPUTS.

The bidirectional function is made with 2 unidirectional Transils T1 and T2. One example with ground on Pin 8 is shown in Fig 6.

This configuration allows to withstand only one specified surge at the same time.



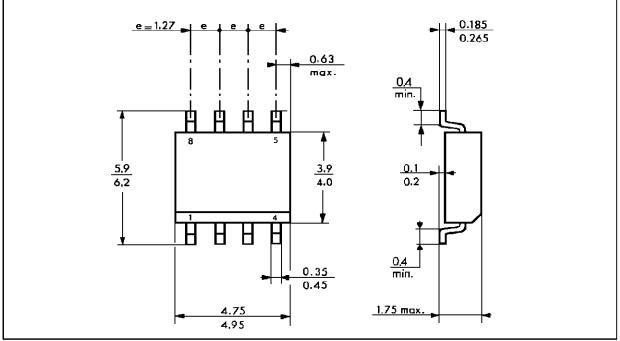
ORDER CODE



MARKING

ТҮРЕ	MARKING
ITA6V5B1	6V5B1
ITA10B1	10B1
ITA18B1	18B1
ITA25B1	25B1

PACKAGE MECHANICAL DATA (in millimeters) SO8 Plastic



Packaging : Products supplied in antistatic tubes.

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